

Excellent Integrated System Limited

Stocking Distributor

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Diodes Incorporated MMST5551-7

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>



Distributor of Diodes Incorporated: Excellent Integrated System Limited Datasheet of MMST5551-7 - TRANS NPN 160V 0.2A SC70-3 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com





MMST5551

Features

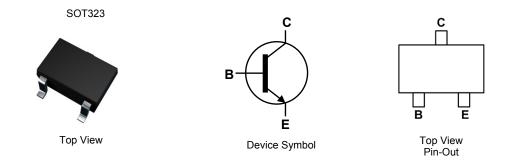
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary NPN Type: MMST5401
- Ideal for Low Power Amplification and Switching
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0

180V NPN SMALL SIGNAL TRANSISTOR IN SOT323

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.006 grams (approximate)



Ordering Information (Notes 4 & 5)

Device	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per reel
MMST5551-7-F	AEC-Q101	K4N	7	8	3,000
MMST5551Q-7-F	Automotive	K4N	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

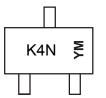
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

 Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K4N = Product Type Marking Code YM = Date Code Marking Y or Y = Year (ex: A = 2013) M or M = Month (ex: 9 = September)

Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	Х		Y	Z		А	В		С	D		E
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D





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Absolute Maximum Ratings	(@T _A = +25°C, unless otherwise specified.)
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Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	180	V
Collector-Emitter Voltage	V _{CEO}	160	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Continuous Collector Current	lc	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 6)	PD	200	mW
Thermal Resistance, Junction to Ambient (Note 6)		R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150	۵°	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)					
Collector-Base Breakdown Voltage	V _{CBO}	180		V	I _C = 100μA, I _E = 0
Collector-Emitter Breakdown Voltage	V _{CEO}	160	_	V	I _C = 1.0mA, I _B = 0
Emitter-Base Breakdown Voltage	V _{EBO}	6.0		V	$I_{\rm E} = 10 \mu A, I_{\rm C} = 0$
Collector Cutoff Current	I _{CBO}	_	50	nA μA	V _{CB} = 120V, I _E = 0 V _{CB} = 120V, I _E = 0, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	_	50	nA	$V_{EB} = 4.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 8)			1	1	+
DC Current Gain	h _{FE}	80 80 30	250 —	_	$ I_{C} = 1.0 \text{mA} , V_{CE} = 5.0 \text{V} \\ I_{C} = 10 \text{mA} , V_{CE} = 5.0 \text{V} \\ I_{C} = 50 \text{mA} , V_{CE} = 5.0 \text{V} $
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.15 0.20	V	$I_{C} = 10mA, I_{B} = 1.0mA$ $I_{C} = 50mA, I_{B} = 5.0mA$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	1.0	V	$I_{C} = 10mA, I_{B} = 1.0mA$ $I_{C} = 50mA, I_{B} = 5.0mA$
SMALL SIGNAL CHARACTERISTICS			•		•
Output Capacitance	C _{obo}	—	6.0	pF	V _{CB} = -10V, f = 1.0MHz, I _E = 0
Small Signal Current Gain	h _{fe}	50	250	_	V _{CE} = 10V, I _C = 1.0mA, f = 1.0kHz
Current Gain-Bandwidth Product	fT	100	300	MHz	V _{CE} = 10V, I _C = 10mA, f = 100MHz
Noise Figure	NF	_	8.0	dB	V_{CE} = 5.0V, I _C = 200µA, R _S =1.0Ω, f = 1.0kHz

Notes: 6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state. 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



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T_A = 25°C

1,000

= -50°C

100

I_C, COLLECTOR CURRENT (mA)

vs. Collector Current

 $T_A = -50^{\circ}C$

TII

T_A = 25°C

10

I_C, COLLECTOR CURRENT (mA)

Fig. 4, Base Emitter Voltage vs. Collector Current

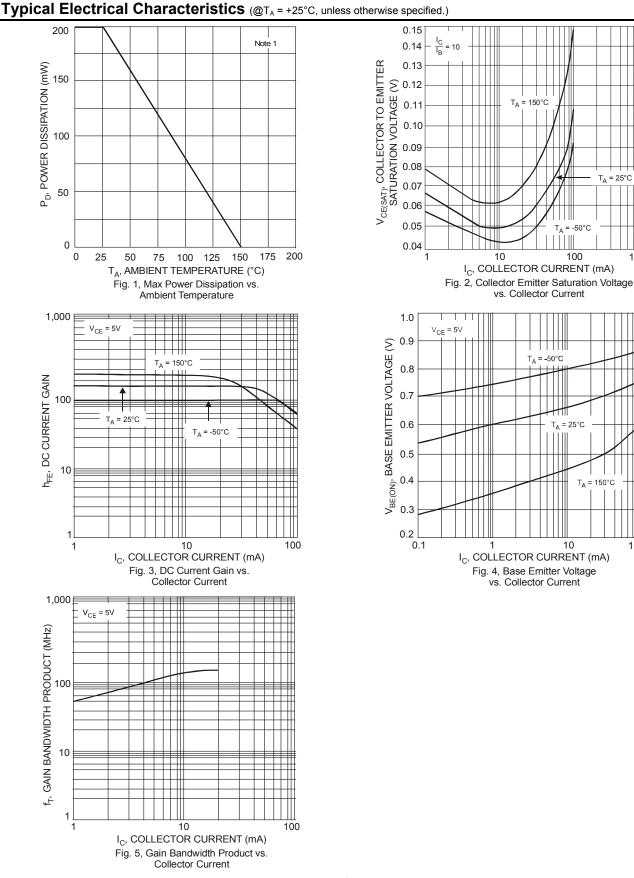
T_A = 150°C

100

T_A = 150°C

10

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MMST5551 Document number: DS30173 Rev. 9 - 2



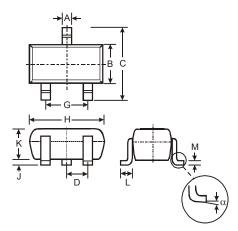
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Package Outline Dimensions

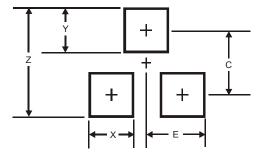
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT	323	
Dim	Min	Max	Тур
Α	0.25	0.40	0.30
в	1.15	1.35	1.30
С	2.00	2.20	2.10
D	-	-	0.65
G	1.20	1.40	1.30
Н	1.80	2.20	2.15
J	0.0	0.10	0.05
κ	0.90	1.00	1.00
L	0.25	0.40	0.30
М	0.10	0.18	0.11
α	0°	8°	-
All	Dimens	ions in	mm

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.





MMST5551

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